FAIRCHILD SEMICONDUCTOR

30V N-Channel PowerTrench^o MOSFET

General Description

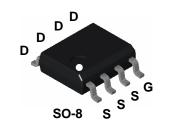
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for "low side" synchronous rectifier operation, providing an extremely low $R_{DS(ON)}$ in a small package.

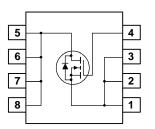
Applications

• DC/DC converter

Features

- 14 A, 30 V. $R_{DS(ON)} = 7.5 \ m\Omega \ @ V_{GS} = 10 \ V$ $R_{DS(ON)} = 9.0 \ m\Omega \ @ V_{GS} = 4.5 \ V$
- Low gate charge (22 nC typical)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Source Voltage			30	
V _{GSS}	Gate-Source Voltage			±20	
I _D	Drain Curre	nt – Continuous	(Note 1a)	14	A
		– Pulsed		50	
P _D	Power Dissipation for Single Operation		(Note 1a)	2.5	W
			(Note 1b)	1.2	
			(Note 1c)	1.0	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		rature Range	-55 to +150	°C
Therma	I Charact	eristics			
R _{eJA}	Thermal Resistance, Junction-to-Ambient (Note 1a)		nt (Note 1a)	50	
R _{θJC}	Thermal Resistance, Junction-to-Case (Note 1)			25	
Packag	e Marking	g and Ordering In	formation		·
Device Marking		Device	Reel Size	Tape width	Quantity
FDS6682		FDS6682	13"	12mm	2500 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics	<u> </u>				
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	30			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		23		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, \qquad V_{GS} = 0 \text{ V}$			10	μA
I _{GSSF}	Gate–Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate–Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1	1.7	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 µA, Referenced to 25°C		-5.6		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = 10 \text{ V}, & I_D = 14 \text{ A} \\ V_{GS} = 4.5 \text{ V}, & I_D = 12.5 \text{ A} \\ V_{GS} = 4.5 \text{ V}, & I_D = 12.5 \text{ A}, \text{ T}_{J} = 125^{\circ}\text{C} \end{array} $		5.7 6.6 8	7.5 9 11.5	mΩ
I _{D(on)}	On–State Drain Current		50			Α
g fs	Forward Transconductance	$V_{DS} = 10 V$, $I_D = 14 A$		70		S
Dvnamio	c Characteristics					
Ciss	Input Capacitance	$V_{DS} = 15 V$, $V_{GS} = 0 V$,		2310		pF
Coss	Output Capacitance	f = 1.0 MHz		582		pF
C _{rss}	Reverse Transfer Capacitance	-		237		pF
Switchir	g Characteristics (Note 2)	•	•	•	•	
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 15 V$, $I_D = 1 A$,		10	20	ns
t _r	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		7	14	ns
t _{d(off)}	Turn–Off Delay Time	-		44	70	ns
t _f	Turn–Off Fall Time	-		16	29	ns
Qg	Total Gate Charge	$V_{DS} = 15 V$, $I_D = 14 A$,		22	31	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = 5 V$		6.4		nC
Q _{gd}	Gate–Drain Charge]		8		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain–Source				2.1	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_{S} = 2.1 A$ (Note 2)		0.7	1.2	V



a) 50°C/W when mounted on a 1in² pad of 2 oz copper

b) 105°C/W when mounted on a .04 in² pad of 2 oz copper

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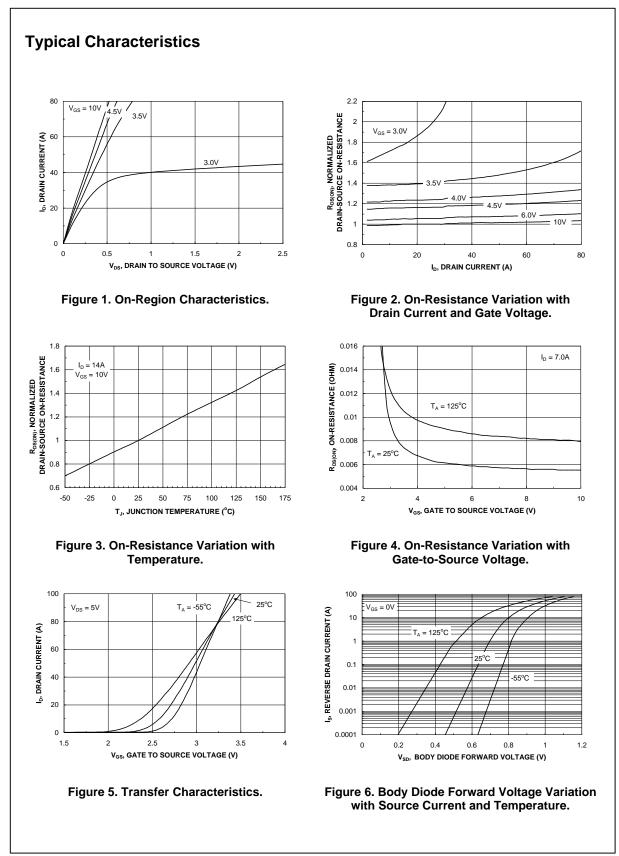
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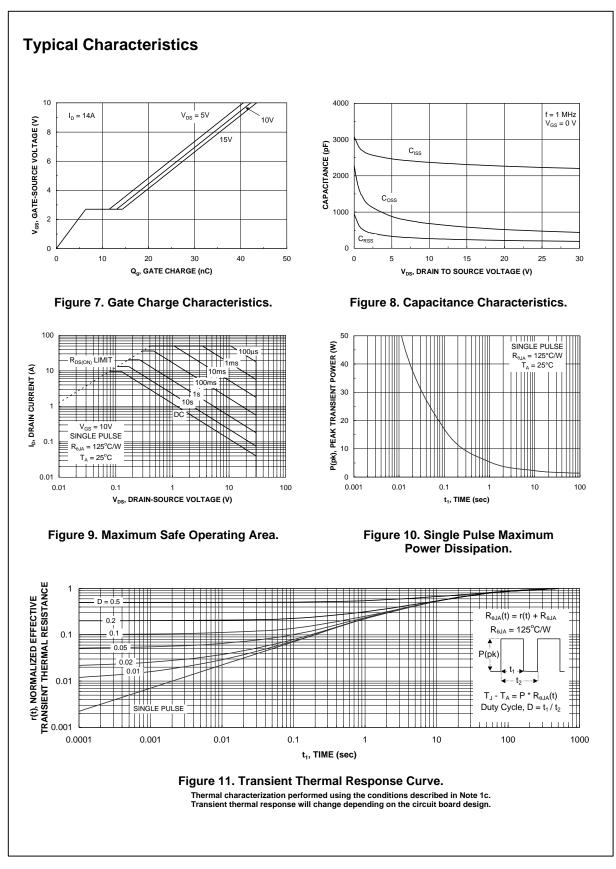
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c) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 $\mu$ s, Duty Cycle < 2.0%





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|--------------------------|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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